New Product



SS8P5C, SS8P6C

Vishay General Semiconductor

High Current Density Surface Mount Dual Common-Cathode Schottky Rectifier



TO-277A (SMPC)

K Anode 1 Cathode Anode 2

PRIMARY CHARACTERISTICS					
I _{F(AV)}	2 x 4.0 A				
V _{RRM}	50 V, 60 V				
I _{FSM}	120 A				
E _{AS}	20 mJ				
V _F at I _F = 4 A	0.56 V				
T _J max.	150 °C				

TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters and polarity protection application.

FEATURES

- Very low profile typical height of 1.1 mm
- Ideal for automated placement
- Low forward voltage drop, low power losses
- High efficiency
- Low thermal resistance
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition

MECHANICAL DATA

Case: TO-277A (SMPC)

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS compliant, and commercial grade

Base P/NHM3 - halogen-free, RoHS compliant, and automotive grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test, HM3 suffix meets JESD 201 class 2 whisker test

MAXIMUM RATINGS ($T_A = 25 \text{ °C}$ unless otherwise noted)						
PARAMETER		SYMBOL	SS8P5C	SS8P6C	UNIT	
Device marking code			S85C	S86C		
Maximum repetitive peak reverse voltage		V _{RRM}	50	60	V	
Maximum average forward rectified current (fig. 1)	total device		8.0		А	
	per diode	IF(AV)	4	.0		
Peak forward surge current 10 ms single half sine-wave superimposed on rated load		I _{FSM}	120		А	
Non-repetitive avalanche energy at 25 °C, I_{AS} = 2 A per diode		E _{AS}	20		mJ	
Operating junction and storage temperature range		T _J , T _{STG}	- 55 to + 150		°C	

AUTOMOTIVE GRADE Available

HALOGEN

SS8P5C, SS8P6C





ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Instantaneous forward voltage per diode	I _F = 2.0 A	T _A = 25 °C	V _F ⁽¹⁾	0.55	-	V	
	I _F = 4.0 A			0.65	0.70		
	I _F = 2.0 A	T _A = 125 °C		0.48	-		
	I _F = 4.0 A			0.56	0.60		
Reverse current per diode	Dated \/	T _A = 25 °C	I _R ⁽²⁾	2.5	50	μA	
	Rated V _R	T _A = 125 °C		1.6	10	mA	
Typical junction capacitance per diode	4.0 V, 1 MHz		CJ	160	-	pF	

Notes

 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 % duty cycle

⁽²⁾ Pulse test: Pulse width \leq 40 ms

THERMAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise specified)						
PARAMETER	SYMBOL	SS8P5C SS8P6C		UNIT		
Typical thermal resistance per diode	$R_{ ext{ hetaJA}}$ (1)	60		°C/W		
	$R_{ ext{ heta}JL}$	3				

Note

⁽¹⁾ Units mounted on recommended PCB 1 oz. pad layout

ORDERING INFORMATION (Example)							
PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE			
SS8P6C-M3/86A	0.10	86A	1500	7" diameter plastic tape and reel			
SS8P6C-M3/87A	0.10	87A	6500	13" diameter plastic tape and reel			
SS8P6CHM3/86A (1)	0.10	86A	1500	7" diameter plastic tape and reel			
SS8P6CHM3/87A ⁽¹⁾	0.10	87A	6500	13" diameter plastic tape and reel			

Note

⁽¹⁾ Automotive grade

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RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 $^{\circ}$ C unless otherwise noted)

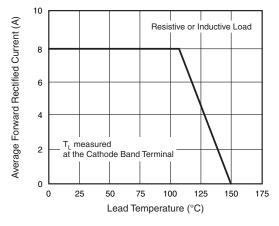


Fig. 1 - Maximum Forward Current Derating Curve

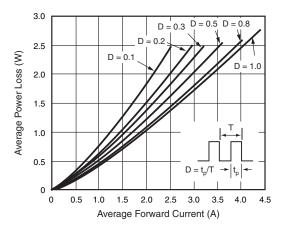


Fig. 2 - Forward Power Loss Characteristics Per Diode

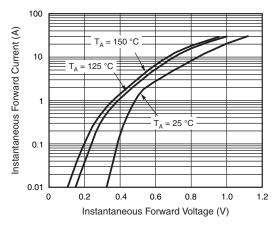


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

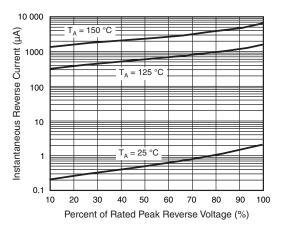


Fig. 4 - Typical Reverse Leakage Characteristics Per Diode

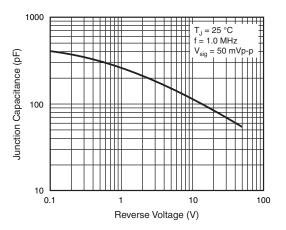
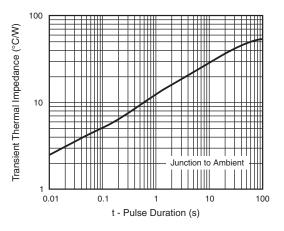


Fig. 5 - Typical Junction Capacitance Per Diode





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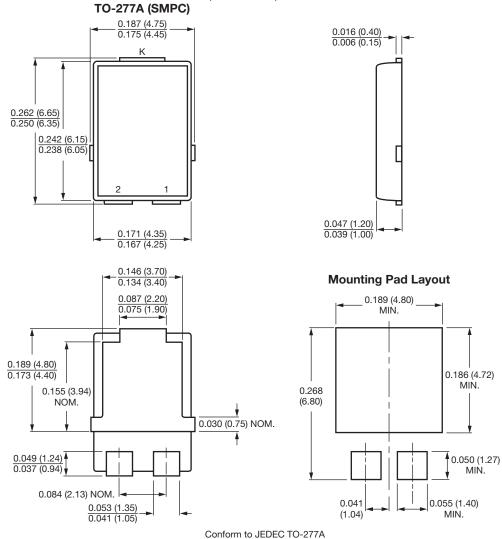
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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



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